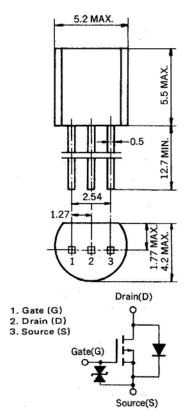


MOS FIELD-EFFECT TRANSISTOR 2SJ178

P-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

OUTLINE DIMENSIONS (Unit: mm)



(Diode in the above figure is a parasitic diode.)

The 2SJ178 is a p-channel vertical type MOS FET switching device which can be directly driven from an IC operating with a 5 V single power supply. The device featuring low ON-state resistance is of the voltage drive type and thus is ideal for driving actuators such as motors, solenoids, and relays.

FEATURES

- Low ON-state resistance
 - $\rm R_{DS(on)}$ = 1.5 Ω MAX. at V $_{GS}$ = -4 V, I $_{D}$ = -0.5 A $\rm R_{DS(on)}$ = 1.0 Ω MAX. at V $_{GS}$ = -10 V, I $_{D}$ = -0.5 A
- Voltage drive at logic level (V_{GS} = -4 V) is possible.
- Bidirectional zener diode for protection is incorporated in between the gate and the source.
- Inductive loads can be driven without protective circuit thanks to the improved breakdown voltage between the drain and source.

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

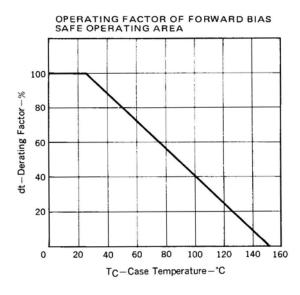
ABSOLUTE MAXIMUM RATINGS $(T_a = 25 \degree C)$

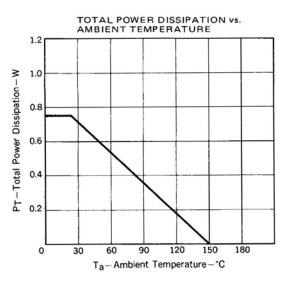
ITEM	SYMBOL	RATING	UNIT	TEST CONDITIONS
Drain to Source Voltage	V _{DSS}	-30	V	V _{GS} = 0
Gate to Source Voltage	V _{GSS}	±20	V	V _{DS} = 0
Drain Current (DC)	ID(DC)	±1.0	А	
Drain Current (pulse)	¹ D(pulse)	±2.0	А	PW ≤10 ms, Duty Cycle ≤ 50 %
Total Power Dissipation	PT	750	mW	T _a = 25 °C
Channel Temperature	T _{ch}	150	°C	
Storage Temperature	T _{stg}	-55 to +150	°C	

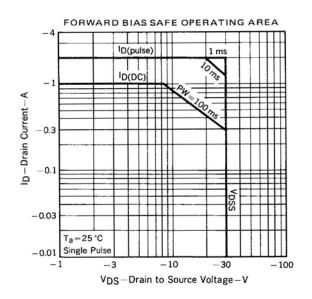
ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

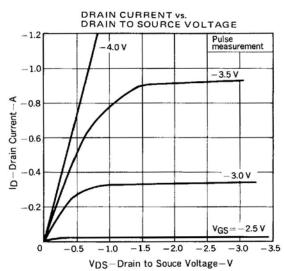
ITEM	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Breaking Current	IDSS			-10	μА	V _{DS} = -30 V, V _{GS} = 0	
Gate Leakage Current	IGSS			∓10	μА	V _{GS} = ¥20 V, V _{DS} = 0	
Gate Cutoff Voltage	VGS(off)	-1.0	-2.2	-3.0	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	
Forward Transfer Admittance	lyfsl	0.4			S	$V_{DS} = -10 \text{ V}, I_{D} = -0.5 \text{ A}$	
Drain to Source ON-State Resistance 1	R _{DS(on)1}		0.8	1.5	Ω	V _{GS} = -4 V, I _D = -0.5 A	
Drain to Source ON-State Resistance 2	RDS(on)2		0.4	1.0	Ω	$V_{GS} = -10 \text{ V}, I_D = -0.5 \text{ A}$	
Input Capacitance	C _{iss}		210		pF		
Output Capacitance	Coss		130		pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	
Feedback Capacitance	C _{rss}		3		pF	1	
ON-State Delay Time	td(on)		35		ns		
Rise Time	t _r		70		ns	$I_D = -0.5 \text{ A}, R_L = 50 \Omega$	
OFF-State Delay Time	td(off)		380		ns	$V_{GS(on)} = -10 \text{ V}$ $R_G = 10 \Omega$, $V_{DD} = -25 \text{ V}$	
Fall Time	tf		200		ns		

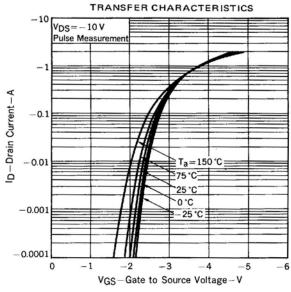
CHARACTERISTIC CURVES ($T_a = 25$ °C)

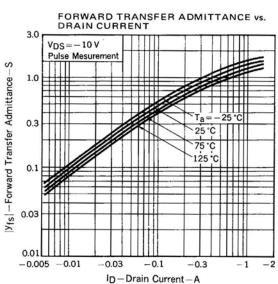


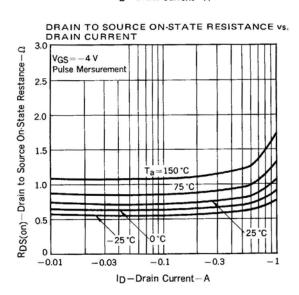


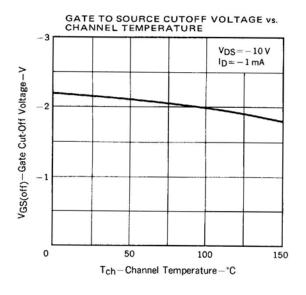


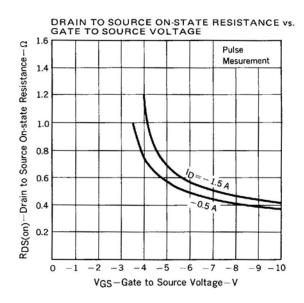


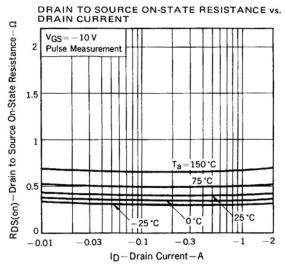


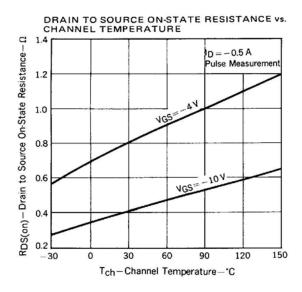


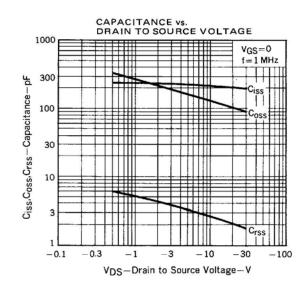


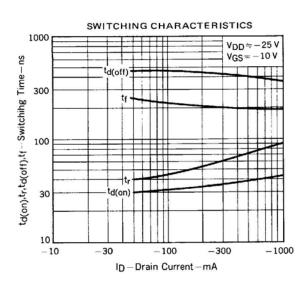


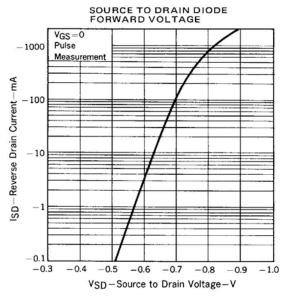




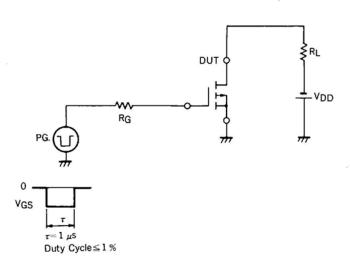


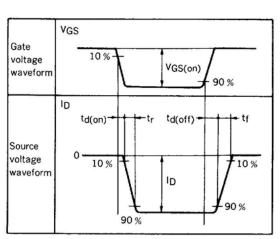






SWITCHING TIME MEASUREMENT CIRCUIT & MEASUREMENT CONDITIONS





RECOMMENDED SOLDERING CONDITIONS

Solder this product under the following recommended conditions.

For soldering methods or soldering conditions other than those recommended in the table, please consult our NEC salespeople.

Insert type

Soldering method	Soldering conditions	Recommended condition code
Wave soldering	Solder bath temperature: 260 °C max. Soldering time: 10 sec max.	

[MEMO]

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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, unclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those inted to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and

Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and

Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.